

Reverse Costing® CATALOGUE

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REVERSE COSTING®

A complete set of information to understand the technology and cost of the electronic devices on the market. System Plus Consulting Reverse Costing® reports are based on in-house developed methodology and costing tools which ensure their single format. The full collection is regularly updated on our website. These reports can be ordered individually or under our Annual Subscription.

IMAGING

Ref.	Date Pages	Manufacturer Product	Type of Product	Overview
VISIBLE				
SP20575	2020/10 84	Polight	TLens MEMS Autofocus	The first polymer-based actuated lens autofocus found in Xiaomi's Smartwatch Camera
SP20573	2020/12 139	Axis P1375-E	Network Camera	Discover Axis's high-end product integrating its latest ARTPEC-7 in-house system-on-chip dedicated to network video and machine learning capabilities.
SP20525	2020/12 250	Various	Smartphone Camera Module Comparison	Evolution of Huawei's smartphone camera released since 2016 with detailed technical and cost analyses of the P40 Pro, P30 Pro, P20 Pro, P10 and P9; Mate 30 Pro and Mate 20 Pro.
SP20518	2020/2 117	Sony	Tof Sensing Solution	Deep analysis of the rear 3D sensing module with Sony's CIS and Lumentum's flood illuminator.
SP20515	2020/4 114	Omnivision OVM6948	CameraCubeChip	Costs and estimates prices for the OVM6948 CameraCubeChip.
SP20505	2020/8 237	Samsung	Smartphone Camera Module Comparison	Evolution of Samsung's smartphone camera since 2016 with detailed technical and cost analyses of the Galaxy S20 Ultra, Galaxy S10+, Galaxy S9+, Galaxy S8, Galaxy S7
SP20484	2020/1 127	Samsung	3D TOF Depth Sensing Camera Module	Deep analysis of the rear 3D sensing module with Sony's 2nd Generation CIS
SP20470	2020/4 145	Various	Smartphone Camera Module Comparison	Overview of the latest flagship smartphone cameras released in 2019 with detailed technical and cost analyses of the Huawei P30 Pro, Samsung Galaxy S10 5G/S10+ and Apple iPhone 11 Pro
SP18385	2018/5 102	ams AS726X Series	Color Sensor	Full analysis from sensor die to packaging along with a cost analysis and a price estimate for the device.
SP18355	2018/7 115	Hamamatsu C12880MA	C12880MA Micro-spectrometer	Detailed physical analysis with process description and manufacturing cost analysis
INFRARED				
SPR2157	2021/1 217	InnoLight DP4CNT	400G Optical Transceiver	Deep analysis of the 400Gb optical transceiver from a leading Chinese company.
SP20571	2020/11 132	Samsung	3D Time-of-Flight Module in Meizu 17 Pro	The first 3D ToF camera from Samsung with Lumentum's VCSEL.
SP20567	2020/9 119	Guide Infrared	17µm Microbolometer Module	Chinese's first low-definition microbolometer for integration into consumer applications
SP20560	2020/8 247	IRay Technology	12µm and 17µm Thermal Sensors	Comparison between 12µm and first and second generation 17µm LWIR microbolometers from Chinese manufacturer IRay Technology's
SP20559	2020/7 115	Hamamatsu	Photodiode and Laser in Livox's Horizon LiDAR	Analysis of the six channels and 905nm pulsed laser and photodiode from Hamamatsu, in Livox's LiDAR for automotive ADAS.

IMAGING

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SP20558	2020/5 123	Nirone	Spectral Engines Nirone Sensor X	Insights into technological data, manufacturing cost, and selling price of housing, electronic board, FPI MEMS and InGaAs photodiode
SP20557	2020/6 174	Apple	iPad Pro LiDAR Module	Complete technical analysis of the 3D depth sensing system, this report analyses the cost and estimates the price for the system
SP20531	2020/6 228	Various	Smartphone 3D Sensing Modules Comparison 2020	Technological and economical comparison of five VCSEL dies and six NIR CIS integrated by the major manufacturers.
SP19488	2019/2 140	Valeo SCALA	Valeo SCALA Laser Scanner	Based on a complete teardown analysis of the LiDAR, the report provides the bill-of-material (BOM) and the manufacturing cost of the LiDAR sensor
SP19468	2019/9 147	pmd/Infineon	pmd/Infineon's 3D Indirect Time-of-Flight in LiDAR	Analysis of the complete 3D indirect ToF camera, provided along with cost analysis and price estimation for the module.
SP19456	2019/4 144	ams	Direct ToF Proximity Sensor	Complete analysis of the proximity sensor includes detailed analyses of the SPAD detector and the VCSEL, along with a cost analysis and price estimation for the module.
SP19451	2019/5 143	Panasonic 3D ToF	3D ToF camera with flood illuminator	Physical and economic analysis of the 3D depth sensing camera found in the Vivo Nex Dual Display smartphone.
SP19431	2019/3 300	Various	Comparison 2019 Mobile CMOS Image Sen	Analysis of the CIS dies integrated in rear and front-facing CMOS Camera Modules including main cameras, wide angle, telephoto and near global shutter infrared.
SP19424	2019/2 180	Huawei Mate 20 Pro	3D Depth-Sensing System	Full analysis of the NIR camera module and the dot projector, along with a cost analysis and price estimate for the system
SP19403	2019/3 147	Sony IMX316	3D Time-of-Flight	Complete 3D depth sensing system physical analysis and cost and estimation of the price.
SP18405	2018/8 200	Samsung & Apple Various	ALS & Proximity Sensor	Analysis of the packaging and the sensor die along with a cost analysis calculation for three smartphone generations: Galaxy S7, S8 and S9 and iPhone 7, 8 and X.
SP18396	2018/4 121	Heimann Sensor HTPA32x32d	32 x 32-array thermopile LWIR	Detailed teardown and cost analysis of the thermopile die, the silicon lens, the EEPROM die, and the packaging.
SP17349	2017/9 170	FLIR Boson	Camera and 12µm microbolometer	Detailed teardown and cost analysis of the microbolometer, lens and WLP. Bill-of-material (BOM) of the camera core, and manufacturing cost of the infrared camera.

INTEGRATED CIRCUITS

Ref.	Date Pages	Manufacturer Product	Type of Product	Overview
OTHER				
SP20608	2020/12 120	Apple	M1 SoC	A deep-dive analysis of Apple's first in-house CPU for Mac.
SP20556	2020/4 92	Mediatek MT2706	77/79 GHz eWLB/AiP Radar Chipset	Review of the MT2706, including a complete package and die analysis, cost analysis, and price estimate for the component
SP20485	2020/1 367	Various	BCD Technology and Cost Comparison 2020	In-depth comparative study of 31 Bipolar-CMOS-DMOS technologies with a focus on Silicon-on-Insulator high voltage devices from the 15 leading manufacturers
SP19462	2019/4 90	Mobileye EyeQ4	Vision Processor Family	Exhaustive comparison between the EyeQ4®-High and -Mid versions and the previous EyeQ3®, highlighting the improvements, similarities and differences.
SP19429	2019/7 100	Melexis MLX90640	Infrared Thermal Sensor	Detailed teardown & cost analysis of the thermopile die where the memory is directly integrated, along with the silicon lens and the packaging.
MEDICAL				
SP19436	2019/6 163	Apple Apple Watch 4	Apple Watch 4's PPG and ECG Health Sensors	Analysis of the complete health sensor system, including a full analysis of the infrared LED from Epistar, green LEDs from OSRAM and the photodiodes from OSRAM for the PPG.

MEMORY

Ref.	Date Pages	Manufacturer Product	Type of Product	Overview
OTHER				
SP20570	2020/12 100	Nanya Technology	8Gb Standard DRAM	Reverse costing report on Nanya's highest density 8Gb DDR4 DRAM memory using 20nm process technology
SP20565	2020/8 90	Samsung LPDDR5	12GB Mobile Memory	In-depth physical and cost analysis of Samsung's '1y-nm' low power DRAM
SP20551	2020/4 130	Intel	Intel Optane 128GB DIMM	Exhaustive analysis of the main components of the Intel Optane DIMM System, including a full analysis of the 3D XPoint die, Intel Optane Processor and the Micron DRAM DDR4 die
SP20543	2020/6 80	Everspin EMD3D256M	STTMRAM Memory	Analysis of the package and the dies, the MRAM cell, focusing on the layered material that makes up the MRAM cell.
SP19466	2019/11 170	Various	LPDDR4 Memory Comparison 2019	Full teardowns of the packages and LPDDR4 dies to unveil the technology and process employed by each manufacturer.
3D NAND				
SP20566	2020/10 95	Micron LPDDR5	12GB Mobile Memory	Physical and cost analysis of Micron's fifth-generation low-power DRAM memory.
SP20562	2020/7 100	YMTC	Technology and cost analysis of YMTC's 64-layer 3D NAND with hybrid bonding.	Technology and cost analysis of YMTC's 64-layer 3D NAND with hybrid bonding.
SP19489	2019/9 100	Samsung	3D V-NAND 92-Layer Memory	Detailed technology study WITH details of die cross sections and material identification, Detailed process and manufacturing price estimation also included.
SP19483	2019/12 240	Various	3D NAND Memory Comparison 2019	Detailed study of the latest 96-layer technology from Toshiba and SanDisk, 92-layer technology from Samsung, 72-layer technology from SK Hynix and 96-layer technology from Micron
SP18422	2018/12 245	Various 3D NAND Memory	Leading-edge 3D NAND Memory Comparison	Detailed study of the latest NAND dies and die cross-section and processes. Detailed physical analysis, highlighting the cell design and memory storage type.

MEMS & SENSOR

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PRINTHEADS				
SP18421	2018/9 150	Xaar 1201 GS2p5 PZT	Xaar 1201 GS2p5 PZT Printhead	Insight into technological data, manu-facturing cost, and selling price of the MEMS inkjet manufactured by Ricoh and the 1201 printhead supplied by Xaar
SP18420	2018/9 158	Epson PrecisionCore	Printhead with MicroTFP Inkjet Dies	Insight into technological data,manufacturing cost, and selling price of the microTFP inkjet MEMS and the PrecisionCore printhead by Epson.
PHOTONIC				
SP20544	2020/3 259	Intel QFSP28	Silicon Photonic 100G CWDMM4	A deep analysis of the world's first 100G CWDMM silicon photonic transceiver, covering new technologies and the main differences from the Intel 100G PSM4.
SP19407	2019/3 200	Intel PSM4 QFSP28	Silicon photonic die	Exhaustive analysis of the main components of the Intel 100G PSM4 connector along with a cost analysis and price estimate.
OTHER				
SP19491	2019/10 88	USound Achelous UT-P 2016	MEMS Speaker	Technology and cost analysis of the UT-P 2016 MEMS Speaker.Envelope Tracker Module
	2019/8 94	HP 746	HP746 HDNA Inkjet Die	Complete physical & cost analysis of the HDNA ihermal inkjet die from HP. A comparison between HP inkjet die with and without HDNA is included.
MICROPHONE				
SP20549	2020/3 112	Infineon XENSIVTM	(SDM) MEMS in Goertek Microphone	Apple's AirPods Pro use the newest MEMS microphone technology from Infineon: Sealed Dual-Membrane XENSIVTM, found in Goertek's microphone.
SP20520	2020/2 113	TDK CH101	Ultrasonic Time of Flight Sensor	The first Piezoelectric Micromachined Ultra-sonic Transducer (PMUT) millimeteraccurate ultra-low power Time of Flight sensor.

MEMS & SENSOR

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SP20458	2020/2 199	Various	Consumer MEMS Microphones	Compare the technology and cost of 19 microphones from Knowles, Goertek, AAC Technologies, STMicroelectronics, TDK-InvenSense, TDK-Epcos, Cirrus Logic and Vesper.
SP19491	2019/10 88	Usound UT-P 2016	MEMS Speaker	Technology and cost analysis of the UT-P 2016 MEMS Speaker
MEDICAL				
SP17346	2017/7 130	Thermo Fisher Ion 520	Sequencing chip	Complete analysis of the Ion 520 chip from Thermo Fisher, featuring chip disassembly and die analyses, processes and cross-sections.
IMU/COMBO				
SP20539	2020/7 131	Sensoror STIM318	Inertial Measurement Unit	Newest IMU with 9-axis detection and gyro bias instability of 0.3°/h from Sensoror.
SP19443	2019/1 102	Honeywell HG1120CA50 9-Axis	MEMS Inertial Sensor	Detailed physical analysis with a process description and manufacturing cost analysis, as well as a full comparison with the Sensoror STIM210 and the ADIS16460.
SP19442	2019/1 161	Honeywell HG4930CA51 6-Axis	MEMS Inertial Sensor	Detailed physical analysis with a process description and manufacturing cost analysis, as well as a full comparison with the Sensoror STIM210 and the HG1120CA50.
SP17361	2017/10 175	InvenSense ICM-20789	Pressure Sensor Combo	Detailed technology and cost analysis of the ICM-20789 7-axis motion tracking device. Comparison with the previous generation of combo sensors from InvenSense
GYROSCOPE				
SP18381	2018/1 141	Tronics Microsystems GYPRO3300	Angular Rate Sensor	Analysis of the complete component, including the package, MEMS, and ASIC dies description of the ASIC and MEMS functionalities.
FINGERPRINT				
SP20552	2020/4 107	Goodix	Goodix's Ultra-Thin Optical In-Display Fingerprint	Deep analysis of the latest generation of under-display optical fingerprint
SP19506	2019/10 160	Goodix	Under-Display Optical Fingerprint	Insight into technological data, manufacturing cost, and selling price of the fingerprint sensor supplied by Goodix.
SP19472	2019/9 271	Various	Piezoelectric modules	Physical analysis and a cost estimation of the integration of piezoelectric material in a system or wafer.
SP19465	2019/7 127	Qualcomm	3D Sonic Sensor Fingerprint	Analyses of the sensor die and the ASICs along with a cost analysis and price estimation for the module.
SP18419	2018/7 125	Synaptics and Goodix VIVO X21	Synaptics' Under-Display Fingerprint Scanner <i>Inside the VIVO X21 UD</i>	Comparison with the latest Huawei FPC1268 fingerprint touch sensor and a physical comparison with the Goodix Version of Vivo's fingerprint scanner
ENVIRONMENT				
SP20513	2020/1 126	Sensirion SCD30	NDIR CO2 and Humidity Sensor	Technology and cost analysis, all the main parts of the sensor are studied, including the humidity sensor, the other module parts and the assembly.
SP20513	2019/1 3990	Sensirion SCD30	NDIR CO2 & Humidity Sensor	Technology and cost analysis that includes study of all the main parts of the sensor : the humidity sensor, the other module parts and the assembly
SP18398	2018/10 150	Various	Miniaturized Gas Sensor	Comparison 2018 : Analysis of the packaging and the sensor die along with a cost analysis for all devices.
SP18372	2018/2 125	Sensirion SGP30	SGP30 Gas Sensor	Analysis of the entire component, including the package, MEMS, and ASIC die. Full description of the ASIC and MEMS functionalities as well as manufacturing processes.
ACCELEROMETER				
SP20568	2020/7 114	Safran & MEMSIC /S1010 & MXA2500N	High-End Accelerometers	Detailed technology and cost analysis of the high-end single-axis and dual-axis accelerometers integrated in the STIM318 IMU.

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OTHER				
SP18430	2018/11 160	Various Wafer	Wafer to Wafer Permanent Bonding	Analysis of each component's wafer bonding process, including component dimensions, cost and manufacturing approach.
EMBEDDED				
SP19425	2019/11 124	Qualcomm QET5100M	Envelope Tracker Module	In-depth physical analysis of the envelope tracking module, and a complete description of the manufacturing process flow
3D PACKAGING				
SP20555	2020/9 190	Intel Core i5-L16G7	Intel Foveros 3D Packaging Technology	Intel Core i5-L16G7: the first utilisation of Intel's Foveros Technology with Package-on-Package configuration in a consumer product.
SP20471	2020/3 220	Apple	SiP in AirPods Pro	Analysis of Apple's first SiP found in the latest AirPods, featuring a fully integrated SiP for audio codec and Bluetooth connectivity.
SP19439	2019/1 200	Apple Series 4	Apple Watch	Complete analysis of the SiP, featuring die analyses, packaging processes and cross-sections.
SP18444	2018/11 127	Samsung Exynos 9110	Samsung Exynos 9110 with Eplp	Complete analysis of the SiP FO-PLP, featuring die analyses, processes and package cross-sections.
SP18417	2018/10 160	Intel	EMIB	Complete physical analysis of the packaging process, with details of all technical choices regarding processes, equipment and materials.
SP18393	2018/7 157	Qualcomm WiGig Chips	Qualcomm WiGig Chipset Smartphone	Full investigation of the system, featuring a detailed study of the SiPs and the antenna board including die analyses, processes and board cross-sections
SP18373	2018/2 140	TSMC Apple A11 inFO PoP	inFO Packaging in iPhone X	Analysis of the packaging from the DRAM memory to the LSC developed by TSMC. Comprehensive cost analysis and price estimation of the device.
SP17360	2017/11 130	AMD Radeon Vega	SPIL CoW last – Samsung HBM2	Complete physical analysis of the packaging process. Comparison with NVIDIA's Tesla P100 and AMD's Fury X.
SP17352	2017/10 300	Various MEMS Packaging	Mems Packaging	Multiple comparisons based on physical analyses of over 100 MEMS components.

PASSIVE

Ref.	Date Pages	Manufacturer Product	Type of Product	Overview
OTHER				
SP17344	2017/9 140	Various Silicon Capacitor	Silicon Capacitor	Details on the manufacturing process and materials used, component design, and die size. Comparison of the components' sizes, materials and characteristics.

POWER

Ref.	Date Pages	Manufacturer Product	Type of Product	Overview
SiC				
SP20537	2020/11 356	Various Various	SiC Transistor Comparison 2020	Compare the technology and cost of 29 SiC transistors from Wolfspeed, Rohm, STMicroelectronics, Infineon, Littelfuse, ON Semiconductor, Microsemi, and UnitedSiC.
SP20536	2020/8 202	Various	SiC Diode Comparison 2020	Comparison of the technology and cost of 11 SiC diodes from Infineon, Wolfspeed, Rohm, STMicroelectronics, ON Semiconductor, Microsemi, UnitedSiC
SP19494	2019/10 154	Wolfspeed CAB450M12XM3	SiC Module	Estimated manufacturing cost of all the module's components and selling price analysis
SP19467	2019/8 200	UnitedSiC	UnitedSiC Cascode JFET 650V Family	Detailed manufacturing cost analysis of the JFET, the MOSFET and the package as well as the estimated selling price of each one of 5 five cascode components
SP19449	2019/5 289	Various SiC MOSFET	Comparison 2019	Estimated manufacturing cost of the MOSFET devices & analysis of their selling prices. Technological & manufacturing cost comparisons between the analyzed MOSFETs.

POWER

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SP18428	2018/8 95	Rohm Gen3 Trench	Rohm SiC MOSFET Gen3 Trench Design Family	Analysis of the Gen3 trench MOSFETs at 650V and 1200V, with optical and scanning electron microscope (SEM) images of the complex SiC trench structure.
SP18413	2018/6 100	STMicroelectronics Tesla Model 3	Tesla Model 3 Inverter with SiC Power Module	Estimation of the production cost of the SiC MOSFET and package. Technical and cost comparison with the Mitsubishi J-Series TP-M power module.
OTHER				
SP20474	2020/5 165	Various	Industrial Power Module Packaging Comparison 2020	Insight into several packaging technologies to analyze their structures, processes and costs
SP18399	2018/7 110	Various	Automotive Power Module Packaging	Comparison 2018 of the structures and costs of the different technological choices made by key manufacturers of the automotive industry
SP18359	2018/5 115	Various	Power Discrete Packaging	Comparison 2018 : Summary of the state of the art of packaging power semiconductors at a discrete level. Comparison of 20 types of packages.
IGBT				
SPR2154	2021/1 287	Various	Si IGBT comparison 2021	Exhaustive technology and cost comparisons of 31 Silicon IGBTs
SP20572	2020/10 125	Infineon FS100R12W2T7	Infineon EasyPACK	Discover the newest IGBT technology from Infineon: TRENCHSTOP™ IGBT7 with EC7 diode in EasyPACK™ module
SP20541	2020/3 100	StarPower GD820HTX75P6H	Tri-Pack IGBT Module	Tri-Pack power module from StarPower with direct liquid cooling pin-fin structure.
SP20516	2020/1 127	Hitachi Audi e-tron's Inverter	Double-Side Cooling Power Module	Discover Hitachi's power module and its innovative assembling technology of integrated double-side cooling structure.
SP19492	2019/10 163	Infineon PrimePACK™2	1200V Power Module with IGBT5 and EC5 Diode	Full teardown of the module's components and housing, as well as estimated manufacturing cost of all the module's components and a selling price analysis
SP19455	2019/3 140	ABB 5SNG 1000X170300	Power Module	Insights into the structure, technical choices, design, processes, and supply chain positions. Manufacturing cost of the module's components and analyses its selling price.
GaN				
SP20580	2020/11 93	STMicroelectronics MASTERGAN1	Half-Bridge Driver	The first 600V system-in-package half-bridge driver from STMicroelectronics integrating two GaN-based HEMTs.
SP20563	2020/7 78	Innoscence	650V GaN-on-Si Transistor	The first 100% Chinese GaN-on-Si power device found in Rock's fast charger, manufactured on an 8-inch platform.
SP20550	2020/3 101	Nexperia GAN063-650WSA	GaNbased Power Device	Deep analysis of the GAN063-650WSA, Nexperia's first GaN product
SP20547	2020/2 127	OPPO	GaN-based in-box fast charger	Competitive analysis of Power Integrations' GaN and silicon technology used in OPPO's high power chargers.
SP20538	2020/10 279	Various Various	GaN Power Transistor Comparison 2020	Comparison of the technology and cost of 18 GaN devices from: EPC, GaN Systems, Infineon, Innoscence, Navitas, Nexperia, Panasonic, Power Integrations, TI
SP19493	2019/10 108	Macom NPA1008	RF Power Amplifier with GaN-on-Si HEMT	Estimation of the production costs of the HEMT, the passive die, and the package as well as the estimated selling price of the component.
SP19480	2019/7 156	Anker SC1933C	GaN-on-Sapphire HEMT Power IC	Teardown analysis of the SC1933C .Estimation of the production costs of the ICs, the HEMT & the package as well as the estimated selling price of the component.
SP19464	2019/5 112	Navitas NV6115 & NV6252	GaNFast Power IC Family	Insights into the HEMT tructure, the epitaxy, technical choices, design, processes, and supply chain positions.
SP19453	2019/7 169	Various	GaN-Based Wall Charger Comparison 2019	Detailed BOM and manufacturing analysis for all the chargers' devices and packages. Different supply chains and the technical choices made by the manufacturers.
SP19415	2019/9 86	EPC EPC2112	HEMT with Monolithic Optimized Gate Driver	Complete teardown analysis and detailed manufacturing cost analysis of the die and the package as well as the estimated selling price of the device,
SP18411	2018/10 110	Qorvo QPF4006 39GHz	Qorvo QPF4006 39GHz GaN MMIC	Detailed analysis of the packaging and the GaN on SiC transistor with optical SEM Pictures as well as a cost analysis.

POWER

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	2019/11 260	Various	GaN-on-Si HEMT vs Superjunction MOSFET Comparison 2019	Detailed pictures of device structures, details on manufacturing processes and materials, comparison of electrical performance, and cost breakdown analysis of the process.
	2019/6 97	Infineon 600V	CoolGaN Transistor	Complete teardown analysis including optical and SEM pictures of metal layers, delayering of the GaN, cross-section of the HEMT part and the diode part of the die.

RF

Ref.	Date Pages	Manufacturer Product	Type of Product	Overview
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RF MODULE

SP20524	2020/11 270	Various Various	RF Front-End Module Comparison 2020 –V4	Technical and cost overview of the latest radio frequency front-end module technologies integrated in Asian based smartphones manufacturers.
SP20523	2020/10 203	Various Various	RF Front-End Module Comparison 2020 –V3	Technical and cost overview of the latest Radio Frequency connectivity Front-End technologies, with deep analysis of Wifi 6.0 and Ultra-Wide Band architecture
SP20522	2020/4 304	Various	RF Front-End Module Comparison 2020 V2	Insights into technology and cost data for FEMs and several other components found in ten smartphones.
SP20504	2020/1 266	various	RF Front-End Module Comparison 2020 – V1	Technical and cost overview of the latest Radio Frequency Front-End module technologies, with deep analysis of the Apple iPhone 11 Pro, Samsung Galaxy Note 10+ and OnePlus 7 Pro 5G.
SP19478	2019/10 162	Qorvo QM76018	RFFEM	Complete analysis of the FEM SiP, including the LNA, the filtering dies, the internal and external EMI shielding and the Power Amplifier.
SP19445	2019/2 167	Broadcom AFEM-8092	Apple iPhone Xs/Xr Series	Complete analysis of the FEM SiP, including an analysis of the matching IC, the filtering dies, the internal and external EMI shielding and the Power Amplifier.
SP19433	2019/5 81	Acconeer A111 60 GHz	Pulsed Coherent Radar	Review of the A111, including a complete die analysis, cost analysis, and price estimate for the chips. Physical and technical comparison with Texas Instruments' IWR6843AoP
SP19400	2019/1 159	Ainstein & Calterah	Ainstein K-77 & Calterah CAL77A2T4R	BOM and the manufacturing cost of the radar sensor and review of the CAL77A2T4R transceiver, with a complete die analysis, cost analysis, and price estimate of the chips.
SP19392	2019/4 121	Analog Devices ADI ADGM 304/1004	RF MEMS Switch	Detailed physical description of the Analog Devices ADGM1304 along with a cost analysis. physical and cost comparison with the ADGM1001.
SP18379	2018/2 160	Broadcom AFEM-8072	Mid&High Band LTE FEM	Analysis of the full FEM SiP, including the RF IC and its IPDs, the filtering dies and the internal and external EMI shielding.
SP18368	2018/10 397	Various Automotive Radar	Automotive Radar	Comparison 2018 : Description of each component and statistical analyses for most radar systems focusing on the RF board.
SP17364	2017/11 140	Various	RF SiPs	Description of each component and important data, including type of substrate, proportion of silicon in the module and line spacing.

RF IC

SP20521	2020/3 205	Broadcom AFEM-8100	SiP in the Apple iPhone 11 Series	Cost effective third generation of mid/high band Front-End Module with advanced and innovative packaging.
SP20519	2020/4 173	Infineon & Knowles T60TR13C & DSP IA85	Google Pixel 4XL Gesture Recognition Chipset	Deep dive into the first Human Machine Interaction (HMI) system with Infineon's 60 GHz Radar On-Chip AoP BGT60TR13C and Knowles' DSP IA8508.
SP20517	2020/5 216	Qualcomm	2nd Generation 5G mmWave Chipset, from Modem to Antenna	Full investigation of the system, featuring a detailed study of the SiPs, including die analyses, processes and board cross-sections
SP19482	2019/9 194	Qualcomm SDX50M & QTM052	Qualcomm's First 5G mmWave Chipset	Full investigation of the system, with detailed study of the SiPs, including die analyses, processes and board cross-sections. Complete cost analysis & selling price estimation. System
SP19481	2019/8 100	Texas Instruments AWR1843AoP	77/79 GHz Radar Chipset	Complete package and die analysis, cost analysis, and price estimate for the component.
SP18418	2018/8 150	Peraso X710	Peraso X710 Chipset 60GHz	Full investigation of the system, with a detailed study of the baseband processor, the RFIC and the antenna board including die analyses, processes and board cross-sections.

RF

Ref.	Date Pages	Manufacturer Product	Type of Product	Overview
RF FILTER				
SP20546	2020/7 100	Skyworks SKY78221	FBAR-BAW Filter Technology in 2G/3G/4G/LTE	First High-Volume Manufacturing (HVM) BAW filter on the market from Skyworks, integrated in the Apple iPhone 11 Pro Max and iPad Pro second generation.
SP20490	2020/6 201	Various	SAW Filter Comparison 2020	Description of each process flow for the thirteen SAW technologies on the market. It also contains a complete cost analysis of each process and tries to explain OEM choices.
SP19454	2019/10 100	Murata IHP	SAW Filter	Complete analysis of the IHP SAW component including analyses of the filter die and the CSP, along with cost analysis and price estimation for the component.
OTHER				
SP20561	2020/9 105	Vayyar VYYR2401	4D UWB Radar Imaging SoC	Deep dive analysis of Vayyar's 4D UWB Radar Imaging System-on-Chip from the Walabot Home Fall Detection System
SP17328	2017/12 300	Various RF IPD	RF Integrated Passive Devices	Description of each component, its major characteristics (substrate type (GaAs, silicon, glass), passivation layers, passive integration, etc.) and a comparison of all devices.

SOLID STATE LIGHTING

Ref.	Date Pages	Manufacturer Product	Type of Product	Overview
VCSEL				
SP19426	2019/4 190	Various VCSEL	Comparison 2019	Complete cost analysis and a cost estimate of the VCSEL
OTHER				
SP20545	2020/4 105	Butterfly Network	CMUT Sensor	Focus on the analysis of the CMUT semiconductor. It includes an ultrasonic MEMS transducer and the ASIC die developed by Butterfly Network.

Headquarters 22 bd Benoni Goullin 44200 Nantes, FRANCE T : +33 2 40 18 09 16 sales@systemplus.fr	Europe Sales Office Lizzie LEVENEZ Frankfurt am Main GERMANY T : +49 151 23 54 41 82 llevenez@systemplus.fr	America Sales Office Steve LAFERRIERE laferriere@yole.fr T : +1 310 600 2867 Troy BLANCHETTE troy.blanchette@yole.fr USA	Asia Sales Office Takashi ONOZAWA Tokyo JAPAN T : +81 3 4405 9204 onozawa@yole.fr	Greater China Office Mavis WANG Taipei TAIWAN T : +886 979 336 809 wang@yole.fr
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